



**SEMIPONT™ 5**

## Three phase antiparallel Thyristor Module

### SKUT 85 T

#### Target Data

#### Features

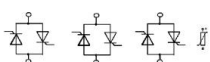
- Compact design
- Two screws mounting
- Heat transfer and isolation through direct copper board (Low  $R_{th}$ )
- Low resistance in Steady-State and high reliability
- High surge currents
- Glass passivated thyristors chips
- Up to 1600V reverse voltage
- UL recognized, file no. E 63 532
- Integrated temperature sensor

#### Typical Applications

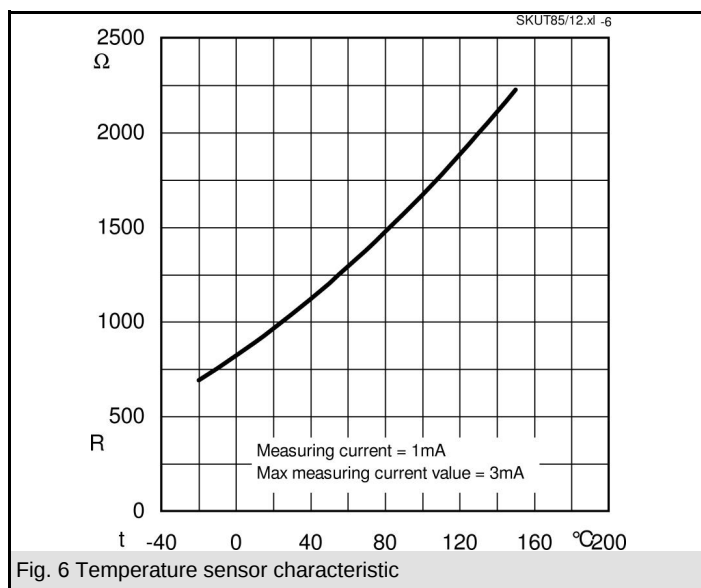
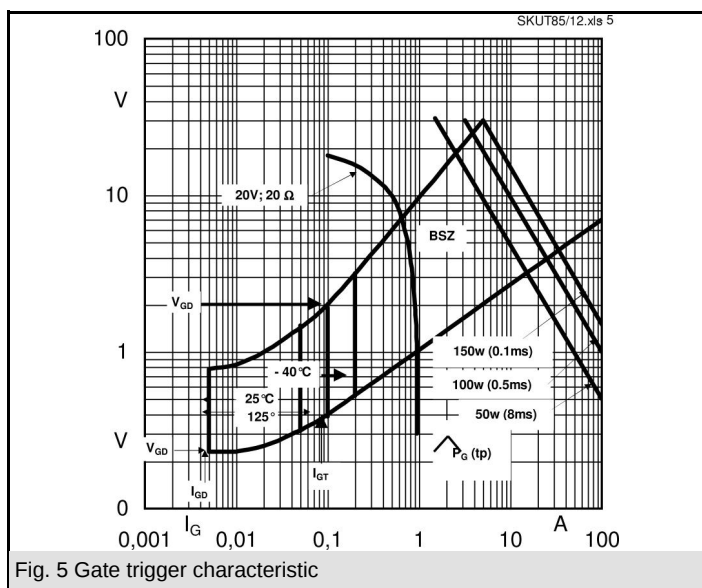
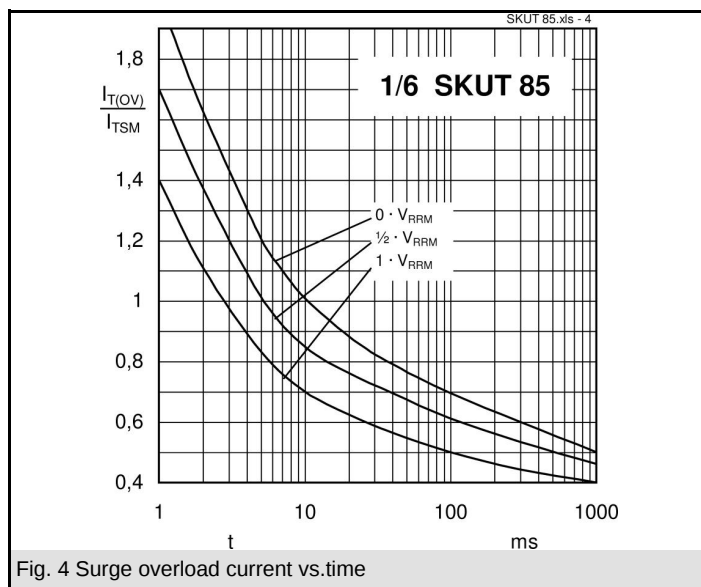
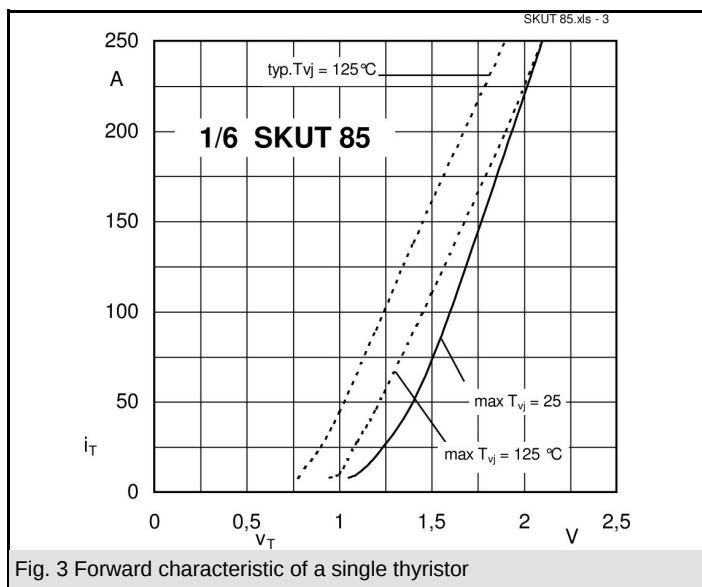
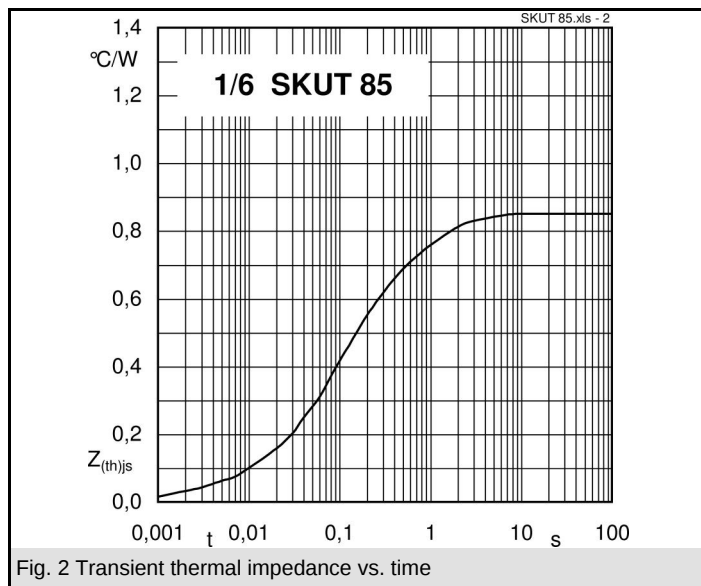
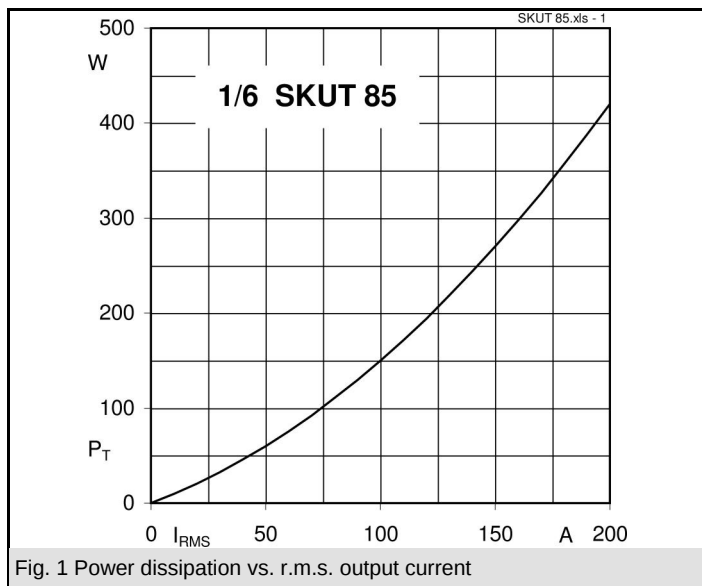
- Soft starter
- Light control (e.g. studios, theaters)
- Temperature control (e.g. oven, chemical processes)

| $V_{RSM}$<br>V | $V_{RRM}, V_{DRM}$<br>V | $I_{RMS} = 85 \text{ A (full conduction)}$<br>( $T_s = 85^\circ \text{C}$ ) |
|----------------|-------------------------|-----------------------------------------------------------------------------|
| 1300           | 1200                    | SKUT 85/12 T                                                                |
| 1700           | 1600                    | SKUT 85/16 T                                                                |

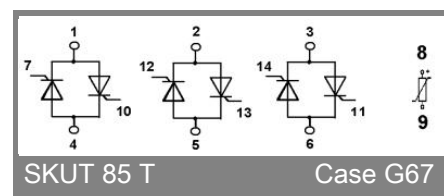
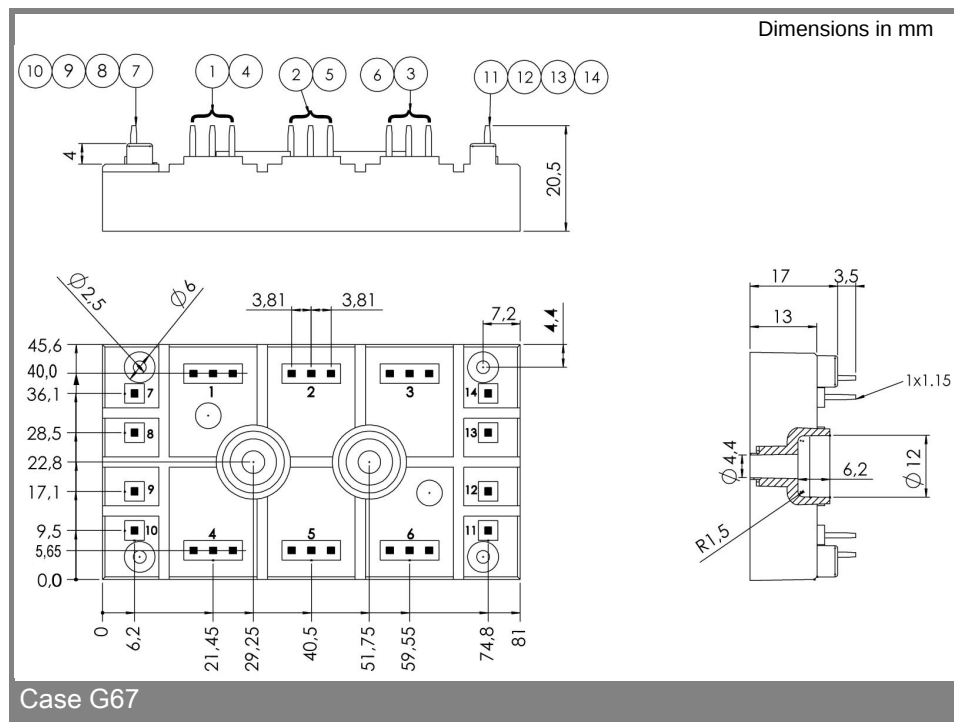
| Symbol             | Conditions                                                                                              | Values            | Units                                |
|--------------------|---------------------------------------------------------------------------------------------------------|-------------------|--------------------------------------|
| $I_{RMS}$          | W3C ; sin. $180^\circ$ ; $T_s = 85^\circ \text{C}$<br>; sin. $180^\circ$ ;                              | 85                | A<br>A                               |
| $I_{TSM}$          | $T_{vj} = 25^\circ \text{C}$ ; 10 ms<br>$T_{vj} = 125^\circ \text{C}$ ; 10 ms                           | 1050              | A<br>A                               |
| $i^2t$             | $T_{vj} = 25^\circ \text{C}$ ; 10 ms<br>$T_{vj} = 125^\circ \text{C}$ ; 8,3...10 ms                     | 5500              | A <sup>2</sup> s<br>A <sup>2</sup> s |
| $V_T$              | $T_{vj} = 25^\circ \text{C}$ , $I_T = 120 \text{ A}$                                                    | max. 1,8          | V                                    |
| $V_{T(TO)}$        | $T_{vj} = 125^\circ \text{C}$                                                                           | max. 1,1          | V                                    |
| $r_T$              | $T_{vj} = 125^\circ \text{C}$                                                                           | max. 6            | mΩ                                   |
| $I_{DD}, I_{RD}$   | $T_{vj} = 25^\circ \text{C}$ , $V_{RD} = V_{RRM}$<br>$T_{vj} = 125^\circ \text{C}$ , $V_{RD} = V_{RRM}$ | max. 1<br>max. 20 | mA<br>mA                             |
| $t_{gd}$           | $T_{vj} = 25^\circ \text{C}$ , $I_G = 1 \text{ A}$ ; $di_G/dt = 1 \text{ A}/\mu\text{s}$                | 1                 | μs                                   |
| $t_{gr}$           | $V_D = 0,67 \cdot V_{DRM}$                                                                              | 2                 | μs                                   |
| $(dv/dt)_{cr}$     | $T_{vj} = 125^\circ \text{C}$                                                                           | 500               | V/μs                                 |
| $(di/dt)_{cr}$     | $T_{vj} = 125^\circ \text{C}$ ; $f = 50...60 \text{ Hz}$                                                | 50                | A/μs                                 |
| $t_q$              | $T_{vj} = 125^\circ \text{C}$ ; typ.                                                                    | 150               | μs                                   |
| $I_H$              | $T_{vj} = 25^\circ \text{C}$ ; typ. / max.                                                              | 200               | mA                                   |
| $I_L$              | $T_{vj} = 25^\circ \text{C}$ ; $R_G = 33 \Omega$ ; typ. / max.                                          | 400               | mA                                   |
| $V_{GT}$           | $T_{vj} = 25^\circ \text{C}$ ; d.c.                                                                     | min. 3            | V                                    |
| $I_{GT}$           | $T_{vj} = 25^\circ \text{C}$ ; d.c.                                                                     | min. 150          | mA                                   |
| $V_{GD}$           | $T_{vj} = 125^\circ \text{C}$ ; d.c.                                                                    | max. 0,25         | V                                    |
| $I_{GD}$           | $T_{vj} = 125^\circ \text{C}$ ; d.c.                                                                    | max. 5            | mA                                   |
| $R_{th(j-s)}$      | sin $180^\circ \text{C}$ per Thyristor                                                                  | 0,85              | K/W<br>K/W                           |
| Temperature sensor | $R_{TS} @ 25^\circ \text{C}$<br>$R_{TS} @ 100^\circ \text{C}$                                           | 1000<br>1670      | Ω<br>Ω                               |
| $T_{vj}$           |                                                                                                         | -40...+125        | °C                                   |
| $T_{stg}$          |                                                                                                         | -40...+125        | °C                                   |
| $T_{sold}$         | Terminals, 10s max                                                                                      | 260               | °C                                   |
| $V_{isol}$         | a. c. 50 Hz; r.m.s.; 1 s / 1 min.                                                                       | 3600 / 3000       | V~                                   |
| $M_s$              | Mounting torque to Heatsink, SI units                                                                   | 2,5               | Nm                                   |
| $M_t$              |                                                                                                         |                   | Nm                                   |
| a                  |                                                                                                         |                   | m/s <sup>2</sup>                     |
| m                  |                                                                                                         | 75                | g                                    |
| Case               | SEMIPONT 5                                                                                              | G67               |                                      |



**W3C**



# SKUT 85 T



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